



NPN PRE-BIASED SMALL SIGNAL SURFACE MOUNT TRANSISTOR

Features

- Epitaxial Planar Die Construction
- Complementary PNP Types Available (DDTA)
- Built-In Biasing Resistor, R2 Only
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Part Number	R2 (NOM)	Marking
DDTC114GE	10kΩ	N26
DDTC124GE	22kΩ	N27
DDTC144GE	47kΩ	N28
DDTC115GE	100kΩ	N29

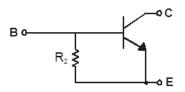
Mechanical Data

- Case: SOT523
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish. Solderable per MIL-STD-202, Method 208@3
- Weight: 0.002 grams (Approximate)

SOT523



Top View



Schematic Diagram

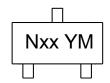
Ordering Information (Note 4)

Part Number	Compliance	Reel Size (inches)	Tape Width (mm)	Quantity Per Reel
DDTC114GE-7-F	AEC-Q101	7	8	3,000
DDTC124GE-7-F	AEC-Q101	7	8	3,000
DDTC144GE-7-F	AEC-Q101	7	8	3,000
DDTC115GF-7-F	AFC-Q101	7	8	3.000

- Notes:
- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

SOT523



Nxx = Product Type Marking Code (See Table in Features) YM = Date Code Marking Y or \overline{Y} = Year (ex: F = 2018) M or \overline{M} = Month (ex: 9 = September)

Date Code Key

Year	2018	2019	20	20	2021	2022	2023	2024	20	25	2026	2027
Code	F	G	ŀ	1	1	J	K	L	ľ	И	N	0
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector Base Voltage	V_{CBO}	50	V
Collector-Emitter Voltage	$V_{\sf CEO}$	50	V
Emitter-Base Voltage	V_{EBO}	5	V
Collector Current	I _C (Max)	100	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation	P _D	150	mW
Thermal Resistance, Junction to Ambient Air (Note 5)	$R_{ hetaJA}$	833	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

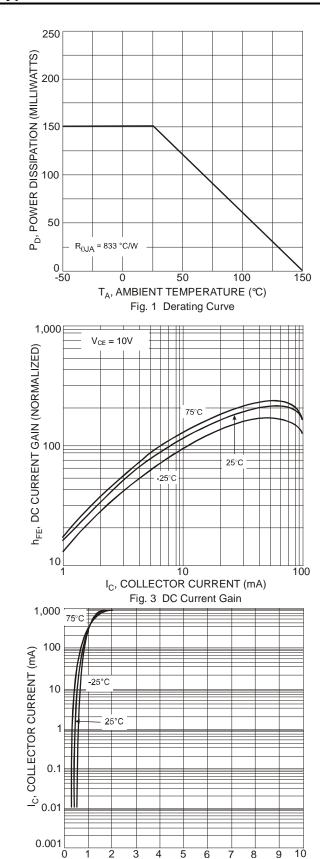
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Volt	age	BV _{CBO}	50	_	_	V	I _C = 50μA
Collector-Emitter Breakdown Vo	oltage	BV _{CEO}	50	_	_	V	I _C = 1mA
Emitter-Base Breakdown Voltage		BV _{EBO}	5	_	_	V	I _E = 720μA, DDTC114GE I _E = 330μA, DDTC124GE I _E = 160μA, DDTC144GE I _E = 72μA, DDTC115GE
Collector Cutoff Current		I _{CBO}	_	_	0.5	μA	V _{CB} = 50V
Emitter Cutoff Current	DDTC114GE DDTC124GE DDTC144GE DDTC115GE	I _{EBO}	300 140 65 30	_	580 260 130 58	μΑ	V _{EB} = 4V
Collector-Emitter Saturation Vo	ltage	V _{CE(SAT)}	_	_	0.3	V	$I_C = 10mA, I_B = 0.5mA$
DC Current Transfer Ratio	DDTC114GE DDTC124GE DDTC144GE DDTC115GE	h _{FE}	30 56 68 82	_	_	_	I _C = 5mA, V _{CE} = 5V
Bleeder Resistor (R ₂) Tolerance		ΔR_2	-30	_	+30	%	_
Gain-Bandwidth Product (Note 6)		f _T	_	250	_	MHz	V _{CE} = 10V, I _E = -5mA, f = 100MHz

5. Mounted on FR-4 PC Board with minimum recommended pad layout. 6. Transistor only. Notes:

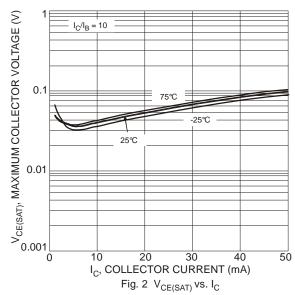


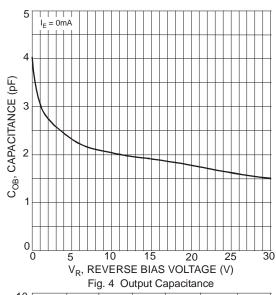
Typical Curves - DDTC114GE

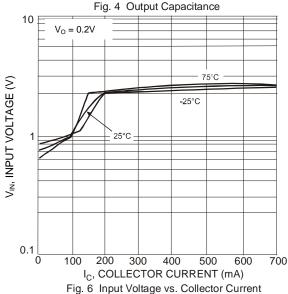


V_{IN}, INPUT VOLTAGE (V)

Fig. 5 Collector Current vs. Input Voltage





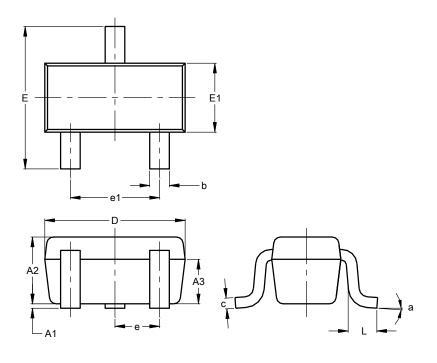




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

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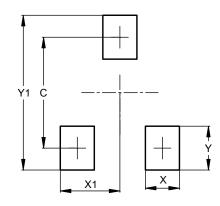


	SOT523						
Dim	Min	Max	Тур				
A1	0.00	0.10	0.05				
A2	0.60	0.80	0.75				
A3	0.45	0.65	0.50				
b	0.15	0.30	0.22				
С	0.10	0.20	0.12				
D	1.50	1.70	1.60				
Е	1.45	1.75	1.60				
E1	0.75	0.85	0.80				
е	0.50 BSC						
e1	0.90	1.10	1.00				
L	0.20	0.40	0.33				
а	0°		8°				
A	All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT523



Dimensions	Value (in mm)		
С	1.29		
Х	0.40		
X1	0.70		
Y	0.51		
Y1	1.80		



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